Reg. No. :

Question Paper Code: 57403

B.E. / B.Tech. DEGREE EXAMINATION, APRIL 2019

Seventh Semester

Electronics and Communication Engineering

15UEC703-MICROWAVE ENGINEERING

(Regulation 2015)

Duration: Three hours

Maximum: 100 Marks

Answer ALL Questions

PART A - (10 x 1 = 10 Marks)

1.	Two microwave devices using Faraday rotation principles are		
	(a) isolator and circulator	(b) circulator and magic tee	
	(c) directional coupler and isolator	(d) none of these	
2.	Which of the following frequency bands frequency?	fall under microwave	CO1-R
	(a) UHF and SHF (b)) SHF and EHF	
	(c) UHF, SHF and EHF (d)) VHF, LF ad MF	
3.	Which type of diodes does not ordinarily operation	ate with reverse bias?	CO2-R
	(a) varactor (b) IMPATT (c) snap-off (d) tunne	1
4.	When a reverse bias voltage exceeding the applied to an IMPATT diode, it results in	e breakdown voltage is	CO2- R
	(a) Avalanche multiplication	(b) Breakdown of depletion region	
	(c) High reverse saturation	(d) None of the mentioned	
5.	Microwave tubes are grouped into two categories depending on the type of		
	(a) Electron beam field interaction	(b) Amplification method	
	(c) Power gain achieved	(d) Construction methods	

6.	A reflex klystron is used as a(n):					CO3-R			
	(a) a	(a) amplifier (b) oscillator							
	(c) r	nixer			(d) fre	equer	ncy multiplie	r	
7.	For are:	the capacitors use	ed in MMICs, th	he insula	ating die	electi	ric films used	đ	CO4-R
	(a) A	Air	(b) SiO						
	(c)]	Fitanium	(d) GaAs						
8.	For the capacitors used in MMIC, the insulating dielectric films are CO						CO4-R		
	(a) <i>A</i>	Air	(b) SiO		(c) Titai	nium	l	(d) GaAs	
9.	mic	in rowave power in a	strument is u microwave cire	sed to cuits.	detect	the	presence o	f	CO5-U
	(a) dete	microwave ctor	(b) attenuator		(c) prob	e		(d) couple	r
10.	The	reflection coeffici	ent on a line is	0.2 angl	e of 45° .	. The	e SWR is		CO5-R
	(a) ().8	(b) 1.1		(c) 1.2			(d) 1.5	
	PART - B (5 x 2 = 10 Marks)								
11.	Define coupling factor and directivity of a directional coupler.						CO1-R		
12.	State Two Valley Model Theory.					CO2-R			
13.	Differentiate Klystron and TWT.					CO3-R			
14.	List out the advantages and applications of MMIC					CO4-R			
15.	5. Write the design considerations for proper operation of spectrum analyzer? CO						CO5-R		
	PART – C (5 x 16= 80 Marks)								
16.	(a)	(i) Prove that it is lossless, reciproc	s not possible to al 3 port junctio	o constru on.	ct a perf	fectly	y matched,	CO1-U	(8)
		(ii) Explain the o	peration of mag	gic tee w Or	ith a nea	at ske	etch	CO1-U	(8)
	(b)	(i) A three port constant of 20dB and VSV	irculator has an WR of 1.2. Calc	insertion	n loss of e S-Matr	f dB, rix of	an isolation f a circulator	CO1-U	(8)
		(ii) Illustrate the	working princip	ole of a H	Faraday	rotat	ion isolator.	CO1-U	(8)
17.	(a)	What are avaland the operation and	che transit time	e devices of IMPA	? Expla TT diod	in ir le.	n detail abour	t CO2-U	(16)

Or

	(b)	With neat diagrams, explain the operation of Tunnel diode and its application as an oscillator and amplifier.	CO2-U	(16)
18.	(a)	(i) Examine the two-cavity klystron amplifier with the effect of velocity and density modulations.	CO3-Ana	(8)
		(ii) A TWT has the following characteristics beam voltage $V_0 = 2$ kV, beam current $I_0 = 4$ mA, frequency, $f = 8$ GHz, circuit length, N = 50 and characteristic impedance $Z_0 = 20\Omega$. Determine	CO3-Ana	(8)
		(a) the gain parameter C and		
		(b) Power gain in decibels.		
		Or		
	(b)	Explain the working principle of Travelling Wave Tube (TWT) amplifiers.	CO3-U	(16)
19.	(a)	Explain the various stages involved in Monolithic Microwave Integrated Circuits technology.	CO4-U	(16)
		Or		(1 c)
	(b)	how matching can be carried out by Microstrip line.	04-0	(16)
20.	(a)	Draw the experimental set – up for s-parameters measurement of magic-T and explain how the s-parameters of a matched magic – T can be determined using Deschamp's method?	CO5-U	(16)
	(b)	Ur Discuss in detail about the impedance measurement using	CO5 U	(16)
	(\mathbf{U})	Discuss in detail about the impedance measurement using	005-0	(10)

microwave devices